



## VND5T100AJ-E

Double channel high-side driver with analog current sense  
for 24 V automotive applications

### Features

|                                   |           |                          |
|-----------------------------------|-----------|--------------------------|
| Max transient supply voltage      | $V_{CC}$  | 58 V                     |
| Operating voltage range           | $V_{CC}$  | 8 to 36 V                |
| Typ on-state resistance (per ch.) | $R_{ON}$  | 100 m $\Omega$           |
| Current limitation (typ)          | $I_{LIM}$ | 22 A                     |
| Off-state supply current          | $I_S$     | 2 $\mu$ A <sup>(1)</sup> |

1. Typical value with all loads connected.

- General
  - Very low standby current
  - 3.0 V CMOS compatible input
  - Optimized electromagnetic emission
  - Very low electromagnetic susceptibility
  - Compliance with European directive 2002/95/EC
  - Fault reset standby pin (FR\_Stby)
- Diagnostic functions
  - Proportional load current sense
  - High current sense precision for wide range currents
  - Off-state open-load detection
  - Output short to  $V_{CC}$  detection
  - Overload and short to ground latch-off
  - Thermal shutdown latch-off
  - Very low current sense leakage
- Protection
  - Undervoltage shutdown
  - Overvoltage clamp
  - Load current limitation
  - Self limiting of fast thermal transients
  - Protection against loss of ground and loss of  $V_{CC}$
  - Thermal shutdown
  - Electrostatic discharge protection



### Application

All types of resistive, inductive and capacitive loads

### Description

The VND5T100AJ-E is a monolithic device made using STMicroelectronics™ VIPower™ technology, intended for driving resistive or inductive loads with one side connected to ground. Active  $V_{CC}$  pin voltage clamp protects the device against low energy spikes.

This device integrates an analog current sense which delivers a current proportional to the load current.

Fault conditions such as overload, overtemperature or short to  $V_{CC}$  are reported via the current sense pin.

Output current limitation protects the device in overload condition. The device latches off in case of overload or thermal shutdown.

The device is reset by a low level pass on the fault reset standby pin.

A permanent low level on the inputs and fault reset standby pin disables all outputs and sets the device in standby mode.

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# 1 Block diagram and pin description

Figure 1. Block diagram

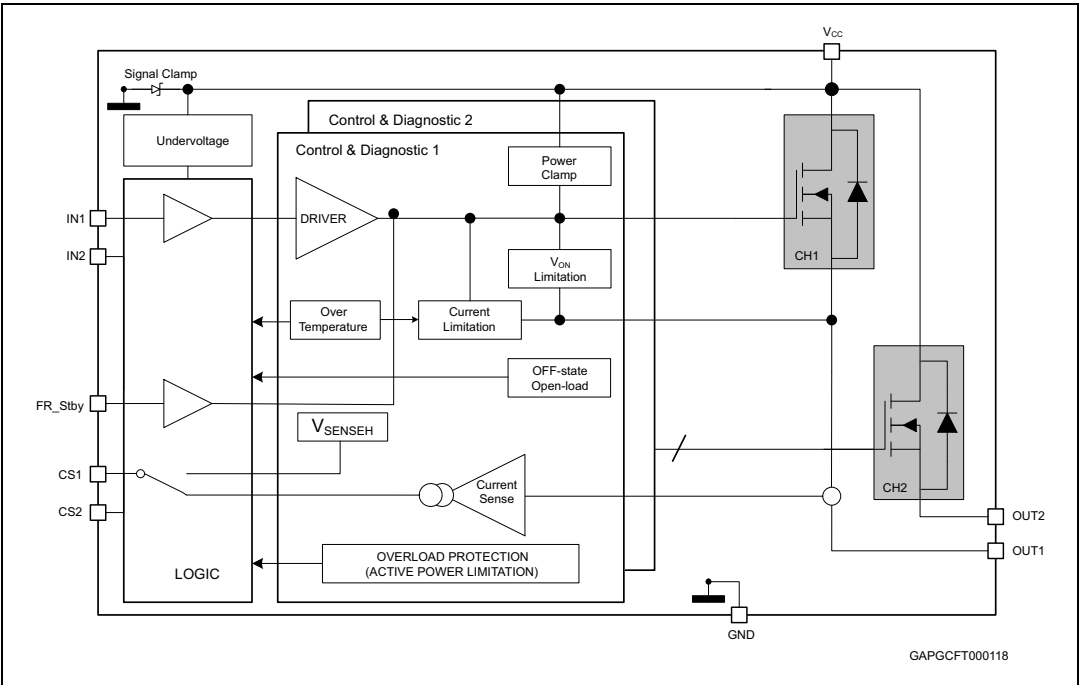


Table 1. Pin function

| Name            | Function                                                                                                                                                                                          |
|-----------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| V <sub>CC</sub> | Battery connection                                                                                                                                                                                |
| OUTn            | Power output                                                                                                                                                                                      |
| GND             | Ground connection                                                                                                                                                                                 |
| INn             | Voltage controlled input pin with hysteresis, CMOS compatible. Controls output switch state                                                                                                       |
| CSn             | Analog current sense pin, delivers a current proportional to the load current                                                                                                                     |
| FR_Stby         | In case of latch-off for OT/overcurrent condition, a low pulse on the FR_Stby pin is needed to reset the channel.<br>The device enters in standby mode if all inputs and the FR_Stby pin are low. |

Figure 2. Configuration diagram (top view)

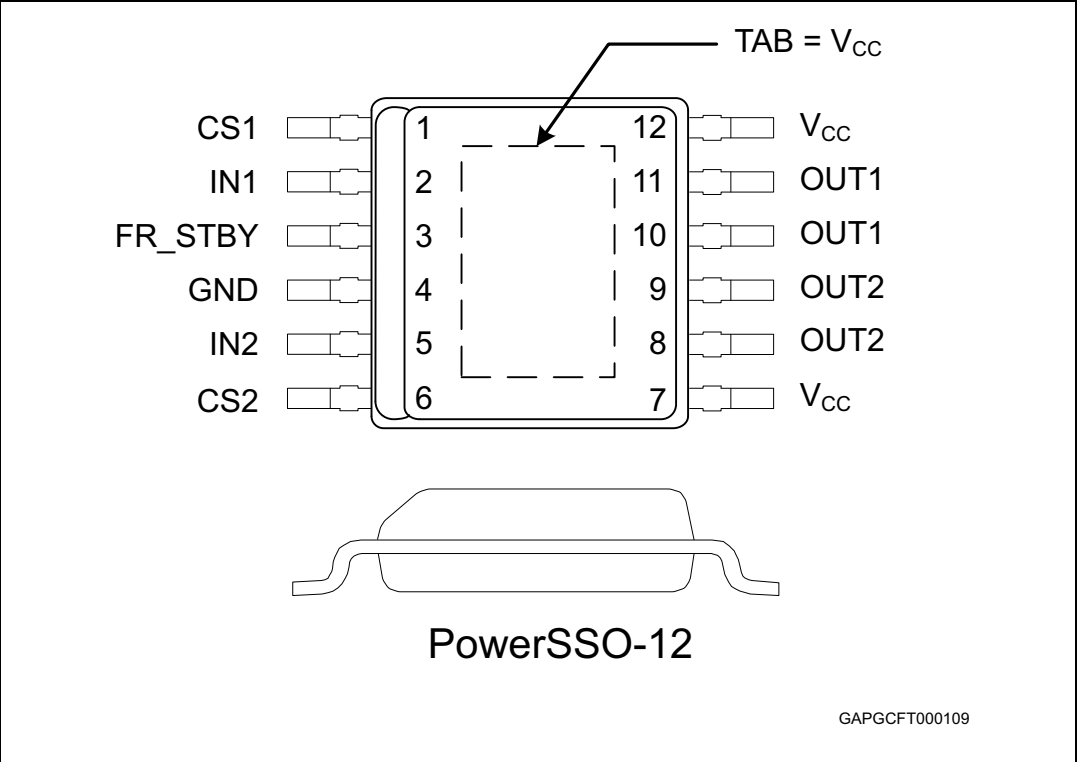
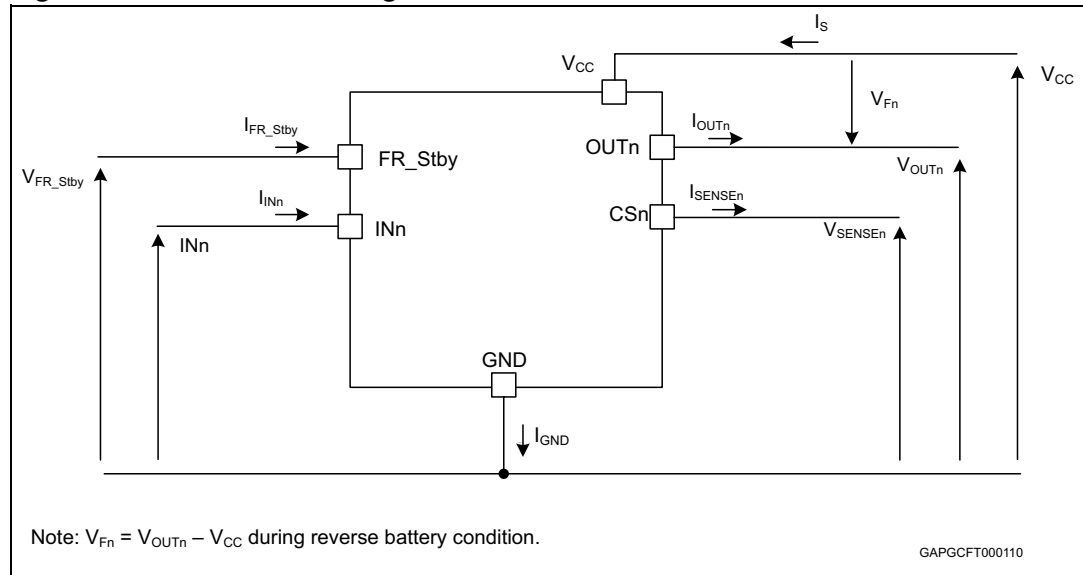


Table 2. Suggested connections for unused and not connected pins

| Connection / pin | Current sense                  | N.C. | Output      | Input                          | FR_Stby                        |
|------------------|--------------------------------|------|-------------|--------------------------------|--------------------------------|
| Floating         | Not allowed                    | X    | X           | X                              | X                              |
| To ground        | Through 10 K $\Omega$ resistor | X    | Not allowed | Through 10 K $\Omega$ resistor | Through 10 K $\Omega$ resistor |

## 2 Electrical specifications

**Figure 3. Current and voltage conventions**



### 2.1 Absolute maximum ratings

Stressing the device above the ratings listed in [Table 3](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to the conditions reported in this section for extended periods may affect device reliability. Refer also to the STMicroelectronics™ SURE program and other relevant quality documents.

**Table 3. Absolute maximum ratings**

| Symbol         | Parameter                            | Value                      | Unit |
|----------------|--------------------------------------|----------------------------|------|
| $V_{CC}$       | DC supply voltage                    | 58                         | V    |
| $-V_{CC}$      | Reverse DC supply voltage            | 0.3                        | V    |
| $-I_{GND}$     | DC reverse ground pin current        | 200                        | mA   |
| $I_{OUT}$      | DC output current                    | Internally limited         | A    |
| $-I_{OUT}$     | Reverse DC output current            | 20                         | A    |
| $I_{IN}$       | DC input current                     | -1 to 10                   | mA   |
| $I_{FR\_Stby}$ | Fault reset standby DC input current | -1 to 1.5                  | mA   |
| $-I_{CSENSE}$  | DC reverse CS pin current            | 200                        | mA   |
| $V_{CSENSE}$   | Current sense maximum voltage        | $V_{CC} - 58$ to $+V_{CC}$ | V    |

**Table 3. Absolute maximum ratings (continued)**

| Symbol     | Parameter                                                                                                                                                                   | Value      | Unit               |
|------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|--------------------|
| $E_{MAX}$  | Maximum switching energy<br>( $L = 1.9 \text{ mH}$ ; $V_{bat} = 32 \text{ V}$ ; $T_{jstart} = 150 \text{ }^{\circ}\text{C}$ ; $I_{OUT} = I_{limL} \text{ (Typ)}$ )          | 70         | mJ                 |
| $V_{ESD}$  | Electrostatic discharge<br>(Human Body Model: $R = 1.5 \text{ K}\Omega$ ; $C = 100 \text{ pF}$ )                                                                            |            |                    |
|            | – INPUT                                                                                                                                                                     | 4000       | V                  |
|            | – CURRENT SENSE                                                                                                                                                             | 2000       | V                  |
|            | – FR_STBY                                                                                                                                                                   | 4000       | V                  |
|            | – OUTPUT                                                                                                                                                                    | 5000       | V                  |
|            | – $V_{CC}$                                                                                                                                                                  | 5000       | V                  |
| $V_{ESD}$  | Charge device model (CDM-AEC-Q100-011)                                                                                                                                      | 750        | V                  |
| $T_j$      | Junction operating temperature                                                                                                                                              | -40 to 150 | $^{\circ}\text{C}$ |
| $T_{stg}$  | Storage temperature                                                                                                                                                         | -55 to 150 | $^{\circ}\text{C}$ |
| $L_{Smax}$ | Maximum stray inductance in short circuit<br>$R_L = 300 \text{ m}\Omega$ , $V_{bat} = 32 \text{ V}$ , $T_{jstart} = 150 \text{ }^{\circ}\text{C}$ , $I_{OUT} = I_{limHmax}$ | 40         | $\mu\text{H}$      |

## 2.2 Thermal data

**Table 4. Thermal data**

| Symbol         | Parameter                                              | Maximum value                 | Unit                 |
|----------------|--------------------------------------------------------|-------------------------------|----------------------|
| $R_{thj-case}$ | Thermal resistance junction-case (with one channel ON) | 3                             | $^{\circ}\text{C/W}$ |
| $R_{thj-amb}$  | Thermal resistance junction-ambient                    | See <a href="#">Figure 27</a> | $^{\circ}\text{C/W}$ |



## 2.3 Electrical characteristics

8 V <  $V_{CC}$  < 36 V; -40 °C <  $T_j$  < 150 °C, unless otherwise specified.

**Table 5. Power section**

| Symbol        | Parameter                          | Test conditions                                                                                  | Min. | Typ.             | Max.             | Unit |
|---------------|------------------------------------|--------------------------------------------------------------------------------------------------|------|------------------|------------------|------|
| $V_{CC}$      | Operating supply voltage           |                                                                                                  | 8    | 24               | 36               | V    |
| $V_{USD}$     | Undervoltage shutdown              |                                                                                                  |      | 3.5              | 5                | V    |
| $V_{USDhyst}$ | Undervoltage shutdown hysteresis   |                                                                                                  |      | 0.5              |                  | V    |
| $R_{ON}$      | On-state resistance <sup>(1)</sup> | $I_{OUT} = 1.5\text{ A}; T_j = 25\text{ °C}$                                                     |      | 100              |                  | mΩ   |
|               |                                    | $I_{OUT} = 1.5\text{ A}; T_j = 150\text{ °C}$                                                    |      |                  | 200              |      |
| $V_{clamp}$   | Clamp voltage                      | $I_S = 20\text{ mA}$                                                                             | 58   | 64               | 70               | V    |
| $I_S$         | Supply current                     | Off-state: $V_{CC} = 24\text{ V}; T_j = 25\text{ °C}; V_{IN} = V_{OUT} = V_{SENSE} = 0\text{ V}$ |      | 2 <sup>(2)</sup> | 5 <sup>(2)</sup> | μA   |
|               |                                    | On-state: $V_{CC} = 24\text{ V}; V_{IN} = 5\text{ V}; I_{OUT} = 0\text{ A}$                      |      | 4.2              | 6                | mA   |
| $I_{L(off)}$  | Off-state output current           | $V_{IN} = V_{OUT} = 0\text{ V}; V_{CC} = 24\text{ V}; T_j = 25\text{ °C}$                        | 0    | 0.01             | 3                | μA   |
|               |                                    | $V_{IN} = V_{OUT} = 0\text{ V}; V_{CC} = 24\text{ V}; T_j = 125\text{ °C}$                       | 0    |                  | 5                |      |
| $V_F$         | Output - $V_{CC}$ diode voltage    | $-I_{OUT} = 1.5\text{ A}; T_j = 150\text{ °C}$                                                   |      |                  | 0.7              | V    |

1. For each channel.

2. PowerMos leakage included

**Table 6. Switching<sup>(1)</sup>**

| Symbol                | Parameter                                 | Test conditions     | Min. | Typ. | Max. | Unit |
|-----------------------|-------------------------------------------|---------------------|------|------|------|------|
| $t_{d(on)}$           | Turn-on delay time                        | $R_L = 16\text{ Ω}$ |      | 27   |      | μs   |
| $t_{d(off)}$          | Turn-off delay time                       | $R_L = 16\text{ Ω}$ |      | 38   |      | μs   |
| $dV_{OUT}/dt_{(on)}$  | Turn-on voltage slope                     | $R_L = 16\text{ Ω}$ |      | 1    |      | V/μs |
| $dV_{OUT}/dt_{(off)}$ | Turn-off voltage slope                    | $R_L = 16\text{ Ω}$ |      | 0.65 |      | V/μs |
| $W_{ON}$              | Switching energy losses during $t_{won}$  | $R_L = 16\text{ Ω}$ |      | 0.23 |      | mJ   |
| $W_{OFF}$             | Switching energy losses during $t_{woff}$ | $R_L = 16\text{ Ω}$ |      | 0.26 |      | mJ   |

1. Operating conditions:  $V_{CC} = 24\text{ V}; T_j = 25\text{ °C}$

**Table 7. Logic inputs**

| Symbol               | Parameter                              | Test conditions                                   | Min. | Typ. | Max. | Unit          |
|----------------------|----------------------------------------|---------------------------------------------------|------|------|------|---------------|
| $V_{IL}$             | Input low level voltage                |                                                   |      |      | 0.9  | V             |
| $I_{IL}$             | Low level input current                | $V_{IN} = 0.9\text{ V}$                           | 1    |      |      | $\mu\text{A}$ |
| $V_{IH}$             | Input high level voltage               |                                                   | 2.1  |      |      | V             |
| $I_{IH}$             | High level input current               | $V_{IN} = 2.1\text{ V}$                           |      |      | 10   | $\mu\text{A}$ |
| $V_{I(hyst)}$        | Input hysteresis voltage               |                                                   | 0.25 |      |      | V             |
| $V_{ICL}$            | Input clamp voltage                    | $I_{IN} = 1\text{ mA}$                            | 5.5  |      | 7    | V             |
|                      |                                        | $I_{IN} = -1\text{ mA}$                           |      | -0.7 |      | V             |
| $V_{FR\_Stby\_L}$    | Fault_reset_standby low level voltage  |                                                   |      |      | 0.9  | V             |
| $I_{FR\_Stby\_L}$    | Low level fault_reset_standby current  | $V_{FR\_Stby} = 0.9\text{ V}$                     | 1    |      |      | $\mu\text{A}$ |
| $V_{FR\_Stby\_H}$    | Fault_reset_standby high level voltage |                                                   | 2.1  |      |      | V             |
| $I_{FR\_Stby\_H}$    | High level fault_reset_standby current | $V_{FR\_Stby} = 2.1\text{ V}$                     |      |      | 10   | $\mu\text{A}$ |
| $V_{FR\_Stby(hyst)}$ | Fault_reset_standby hysteresis voltage |                                                   | 0.25 |      |      | V             |
| $V_{FR\_Stby\_CL}$   | Fault_reset_standby clamp voltage      | $I_{FR\_Stby} = 15\text{ mA (} t < 10\text{ ms)}$ | 11   |      | 15   | V             |
|                      |                                        | $I_{FR\_Stby} = -1\text{ mA}$                     |      | -0.7 |      | V             |
| $t_{reset}$          | Overload latch-off reset time          | See <a href="#">Figure 4</a>                      | 2    |      | 24   | $\mu\text{s}$ |
| $t_{stby}$           | Standby delay                          | See <a href="#">Figure 5</a>                      | 120  |      | 1200 | $\mu\text{s}$ |

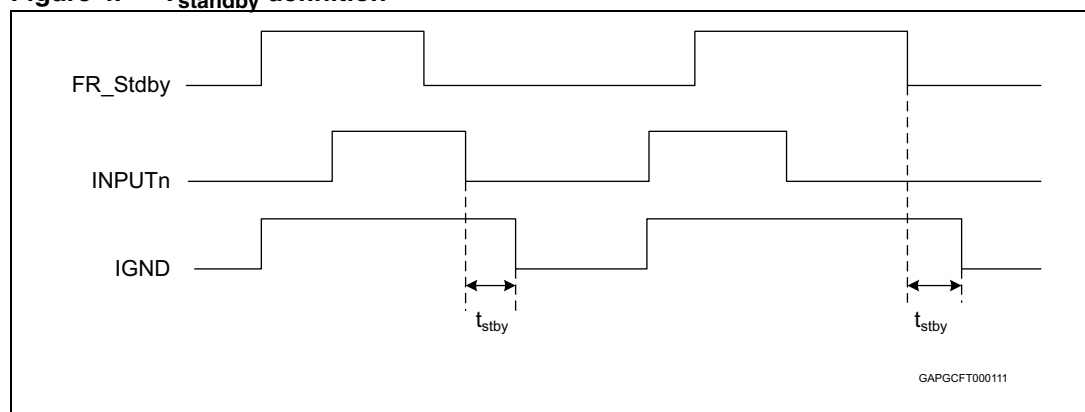
**Figure 4.  $T_{standby}$  definition**

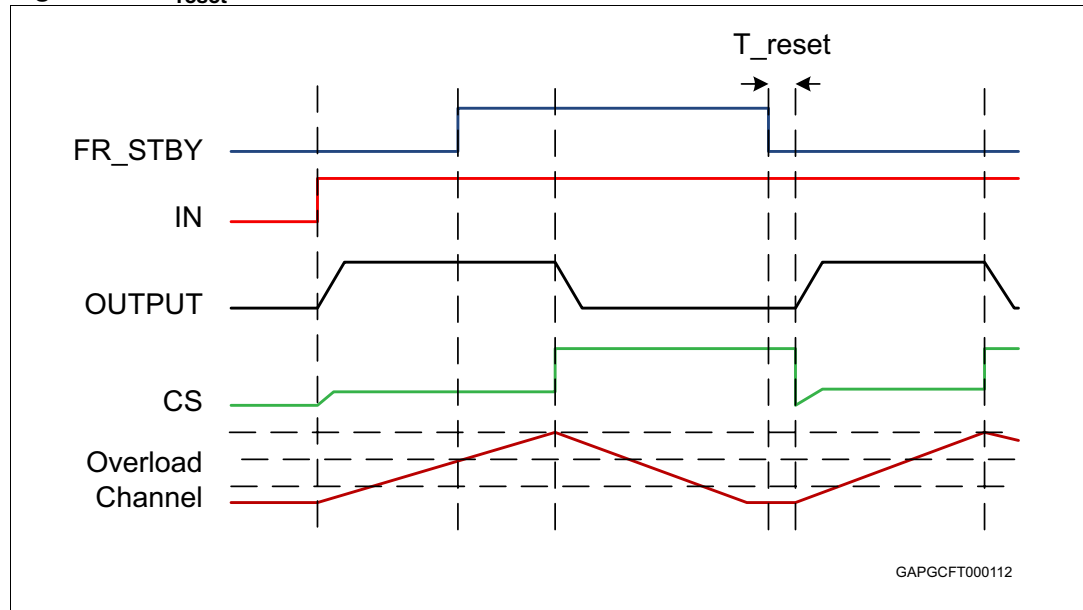
Figure 5.  $T_{\text{reset}}$  definition

Table 8. Protections and diagnostics

| Symbol             | Parameter                                              | Test conditions                                                                                                        | Min.                 | Typ.                 | Max.                 | Unit   |
|--------------------|--------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------|----------------------|----------------------|----------------------|--------|
| $I_{\text{limH}}$  | DC short circuit current                               | $V_{\text{CC}} = 24 \text{ V}$<br>$5 \text{ V} < V_{\text{CC}} < 36 \text{ V}$                                         | 16                   | 22                   | 30<br>30             | A<br>A |
| $I_{\text{limL}}$  | Short circuit current during thermal cycling           | $V_{\text{CC}} = 24 \text{ V};$<br>$T_{\text{R}} < T_{\text{j}} < T_{\text{TSD}}$                                      |                      | 6                    |                      | A      |
| $T_{\text{TSD}}$   | Shutdown temperature                                   |                                                                                                                        | 150                  | 175                  | 200                  | °C     |
| $T_{\text{R}}$     | Reset temperature                                      |                                                                                                                        | $T_{\text{RS}} + 1$  | $T_{\text{RS}} + 5$  |                      | °C     |
| $T_{\text{RS}}$    | Thermal reset of status                                |                                                                                                                        | 135                  |                      |                      | °C     |
| $T_{\text{HYST}}$  | Thermal hysteresis ( $T_{\text{TSD}} - T_{\text{R}}$ ) |                                                                                                                        |                      | 7                    |                      | °C     |
| $V_{\text{DEMAG}}$ | Turn-off output voltage clamp                          | $I_{\text{OUT}} = 1.5 \text{ A}; V_{\text{IN}} = 0;$<br>$L = 6 \text{ mH}$                                             | $V_{\text{CC}} - 58$ | $V_{\text{CC}} - 64$ | $V_{\text{CC}} - 70$ | V      |
| $V_{\text{ON}}$    | Output voltage drop limitation                         | $I_{\text{OUT}} = 50 \text{ mA};$<br>$T_{\text{j}} = -40 \text{ }^{\circ}\text{C} \dots +150 \text{ }^{\circ}\text{C}$ |                      | 25                   |                      | mV     |

**Table 9. Current sense (8 V < V<sub>CC</sub> < 36 V)**

| Symbol                                         | Parameter                                                     | Test conditions                                                                                                                                                         | Min.         | Typ.         | Max.         | Unit     |
|------------------------------------------------|---------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|--------------|--------------|----------|
| K <sub>1</sub>                                 | I <sub>OUT</sub> /I <sub>SENSE</sub>                          | I <sub>OUT</sub> = 350 mA; V <sub>SENSE</sub> = 1 V;<br>T <sub>j</sub> = -40 °C...150 °C<br>T <sub>j</sub> = 25 °C...150 °C                                             | 930<br>1050  | 1547<br>1547 | 2185<br>2020 |          |
| dK <sub>1</sub> /K <sub>1</sub> <sup>(1)</sup> | Current sense ratio drift                                     | I <sub>OUT</sub> = 350 mA; V <sub>SENSE</sub> = 1 V;<br>T <sub>j</sub> = -40 °C to 150 °C                                                                               | -15          |              | 15           | %        |
| K <sub>2</sub>                                 | I <sub>OUT</sub> /I <sub>SENSE</sub>                          | I <sub>OUT</sub> = 0.8 A; V <sub>SENSE</sub> = 2 V;<br>T <sub>j</sub> = -40 °C...150 °C<br>T <sub>j</sub> = 25 °C...150 °C                                              | 1225<br>1310 | 1528<br>1528 | 1835<br>1745 |          |
| dK <sub>2</sub> /K <sub>2</sub> <sup>(1)</sup> | Current sense ratio drift                                     | I <sub>OUT</sub> = 0.8 A; V <sub>SENSE</sub> = 2 V;<br>T <sub>j</sub> = -40 °C to 150 °C                                                                                | -12          |              | 12           | %        |
| K <sub>3</sub>                                 | I <sub>OUT</sub> /I <sub>SENSE</sub>                          | I <sub>OUT</sub> = 1.5 A; V <sub>SENSE</sub> = 2 V;<br>T <sub>j</sub> = -40 °C...150 °C<br>T <sub>j</sub> = 25 °C...150 °C                                              | 1340<br>1405 | 1525<br>1525 | 1715<br>1655 |          |
| dK <sub>3</sub> /K <sub>3</sub> <sup>(1)</sup> | Current sense ratio drift                                     | I <sub>OUT</sub> = 1.5 A; V <sub>SENSE</sub> = 2 V;<br>T <sub>j</sub> = -40 °C to 150 °C                                                                                | -8           |              | 8            | %        |
| K <sub>4</sub>                                 | I <sub>OUT</sub> /I <sub>SENSE</sub>                          | I <sub>OUT</sub> = 6 A; V <sub>SENSE</sub> = 4 V;<br>T <sub>j</sub> = -40 °C...150 °C<br>T <sub>j</sub> = 25 °C...150 °C                                                | 1450<br>1475 | 1522<br>1522 | 1600<br>1560 |          |
| dK <sub>4</sub> /K <sub>4</sub> <sup>(1)</sup> | Current sense ratio drift                                     | I <sub>OUT</sub> = 6 A; V <sub>SENSE</sub> = 4 V;<br>T <sub>j</sub> = -40 °C to 150 °C                                                                                  | -5           |              | 5            | %        |
| I <sub>SENSE0</sub>                            | Analog sense leakage current                                  | I <sub>OUT</sub> = 0 A; V <sub>SENSE</sub> = 0 V;<br>V <sub>IN</sub> = 0 V; T <sub>j</sub> = -40 °C...150 °C<br>V <sub>IN</sub> = 5 V; T <sub>j</sub> = -40 °C...150 °C | 0<br>0       |              | 1<br>2       | μA<br>μA |
| V <sub>SENSE</sub>                             | Max analog sense output voltage                               | I <sub>OUT</sub> = 6 A; R <sub>SENSE</sub> = 3.9 KΩ                                                                                                                     | 5            |              |              | V        |
| V <sub>SENSEH</sub>                            | Analog sense output voltage in fault condition <sup>(2)</sup> | V <sub>CC</sub> = 24 V; R <sub>SENSE</sub> = 3.9 KΩ                                                                                                                     | 7.5          | 8.5          | 9.5          | V        |
| I <sub>SENSEH</sub>                            | Analog sense output current in fault condition <sup>(2)</sup> | V <sub>CC</sub> = 24 V; V <sub>SENSE</sub> = 5 V                                                                                                                        | 4.9          | 9            | 12           | mA       |
| t <sub>DSENSE2H</sub>                          | Delay response time from rising edge of INPUT pin             | V <sub>SENSE</sub> < 4 V, 0.07 A < I <sub>OUT</sub> < 6 A<br>I <sub>SENSE</sub> = 90 % of I <sub>SENSE max</sub><br>(see <a href="#">Figure 6</a> )                     |              | 100          | 200          | μs       |

**Table 9. Current sense (8 V < V<sub>CC</sub> < 36 V) (continued)**

| Symbol                       | Parameter                                                                                  | Test conditions                                                                                                                                                                                                                      | Min. | Typ. | Max. | Unit          |
|------------------------------|--------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $\Delta t_{\text{DSENSE2H}}$ | Delay response time between rising edge of output current and rising edge of current sense | $V_{\text{SENSE}} < 4 \text{ V}$ ,<br>$I_{\text{SENSE}} = 90 \% \text{ of } I_{\text{SENSEMAX}}$ ,<br>$I_{\text{OUT}} = 90 \% \text{ of } I_{\text{OUTMAX}}$<br>$I_{\text{OUTMAX}} = 1.5 \text{ A}$ (see <a href="#">Figure 11</a> ) |      |      | 150  | $\mu\text{s}$ |
| $t_{\text{DSENSE2L}}$        | Delay response time from falling edge of INPUT pin                                         | $V_{\text{SENSE}} < 4 \text{ V}$ , $0.07 \text{ A} < I_{\text{OUT}} < 6 \text{ A}$<br>$I_{\text{SENSE}} = 10 \% \text{ of } I_{\text{SENSE max}}$<br>(see <a href="#">Figure 6</a> )                                                 |      | 5    | 20   | $\mu\text{s}$ |

- Parameter guaranteed by design; it is not tested.
- Fault condition includes: power limitation, overtemperature and open-load in OFF-state condition.

**Table 10. Open-load detection**

| Symbol                  | Parameter                                                                             | Test conditions                                                                                                                                                                                                | Min. | Typ. | Max. | Unit          |
|-------------------------|---------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{\text{OL}}$         | Open-load off-state voltage detection threshold                                       | $V_{\text{IN}} = 0 \text{ V}$ ; $8 \text{ V} < V_{\text{CC}} < 36 \text{ V}$ ;<br>$F_{\text{R\_STBY}} = 5 \text{ V}$                                                                                           | 2    |      | 4    | V             |
| $t_{\text{DSTKON}}$     | Output short circuit to V <sub>CC</sub> detection delay at turn off                   | See <a href="#">Figure 6</a> ;<br>$F_{\text{R\_STBY}} = 5 \text{ V}$                                                                                                                                           | 180  |      | 1800 | $\mu\text{s}$ |
| $t_{\text{DFRSTK\_ON}}$ | Output short circuit to V <sub>CC</sub> detection delay at FRSTBY activation          | See <a href="#">Figure 9</a> ; Input <sub>1,2</sub> = low                                                                                                                                                      |      |      | 50   | $\mu\text{s}$ |
| $I_{\text{L(off2)}}$    | Off-state output current at V <sub>OUT</sub> = 4V                                     | $V_{\text{IN}} = 0 \text{ V}$ ; $V_{\text{SENSE}} = 0 \text{ V}$ ;<br>$V_{\text{OUT}}$ rising from 0 V to 4 V;<br>$F_{\text{R\_STBY}} = 5 \text{ V}$                                                           | -120 |      | 0    | $\mu\text{A}$ |
| $t_{\text{d\_vol}}$     | Delay response from output rising edge to V <sub>SENSE</sub> rising edge in open-load | $V_{\text{OUT}} = 4 \text{ V}$ ; $V_{\text{IN}} = 0 \text{ V}$<br>$V_{\text{SENSE}} = 90 \% \text{ of } V_{\text{SENSEH}}$<br>$R_{\text{SENSE}} = 3.9 \text{ K}\Omega$ ;<br>$F_{\text{R\_STBY}} = 5 \text{ V}$ |      |      | 20   | $\mu\text{s}$ |

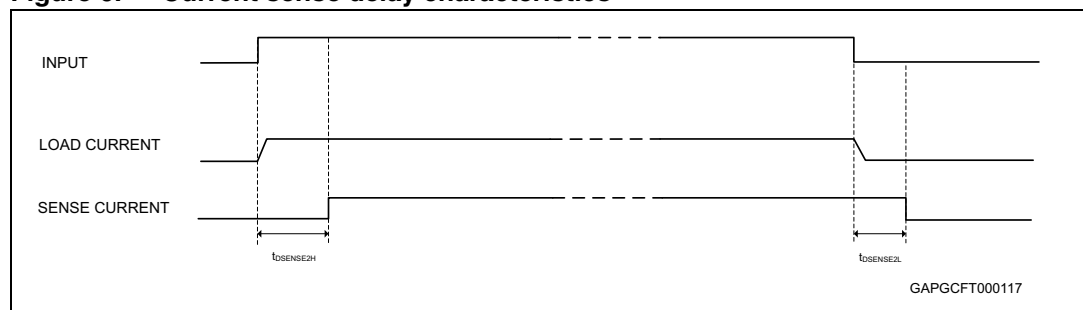
**Figure 6. Current sense delay characteristics**

Figure 7. Open-load off-state delay timing

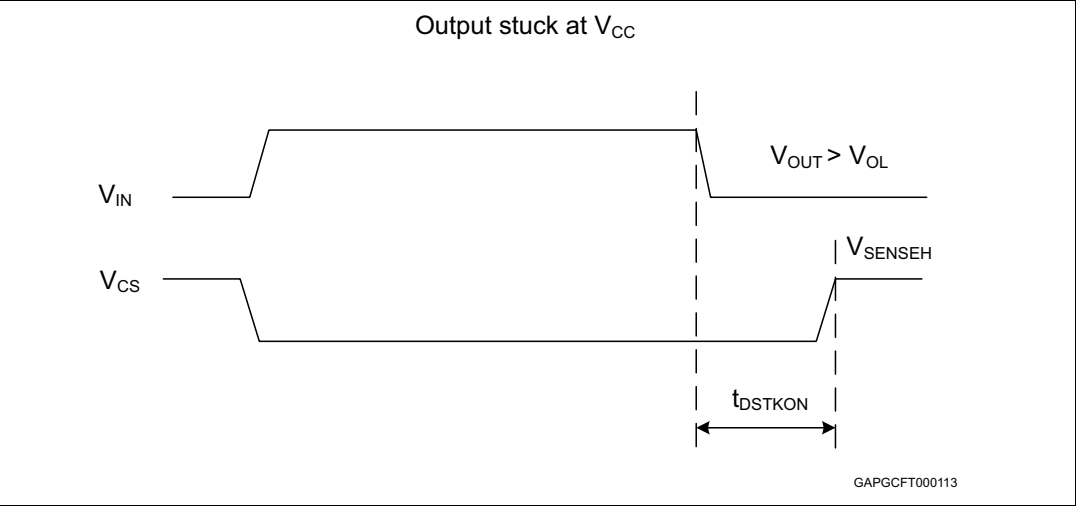


Figure 8. Switching characteristics

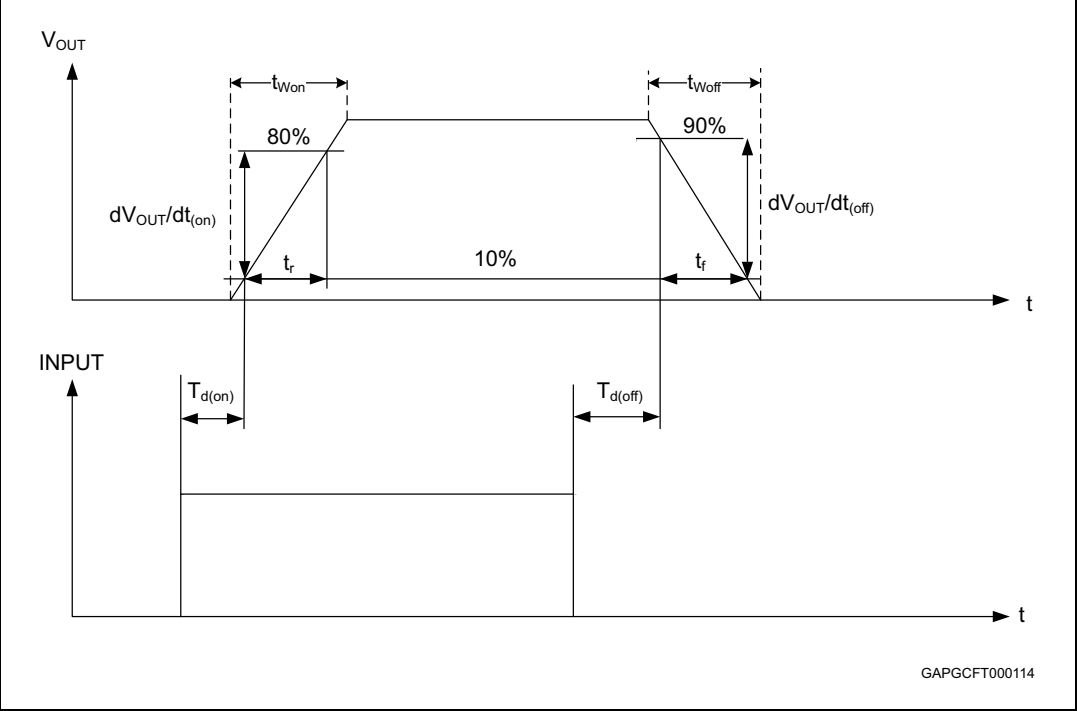


Figure 9. Output stuck to  $V_{CC}$  detection delay time at FRSTBY activation

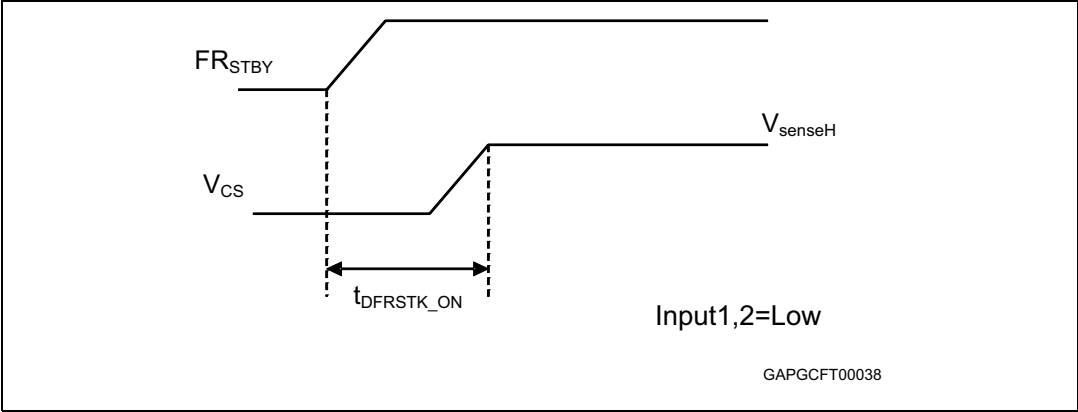


Figure 10. Delay response time between rising edge of output current and rising edge of current sense

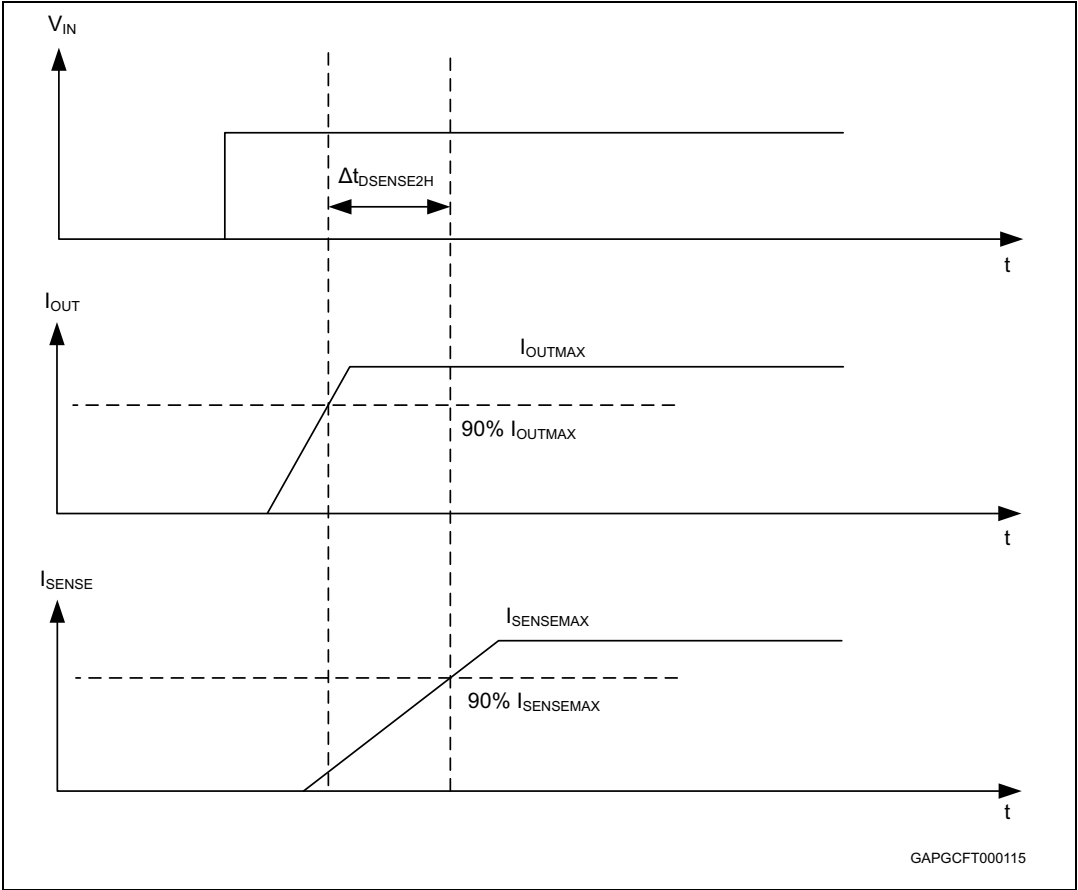


Figure 11. Output voltage drop limitation

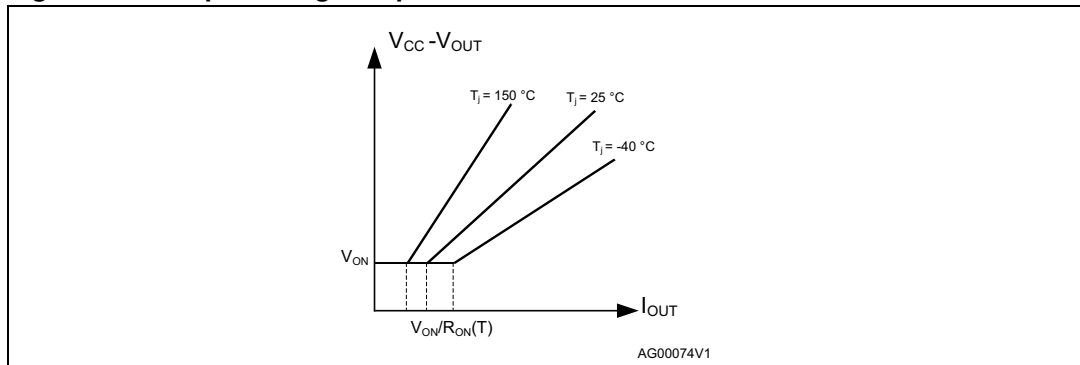


Figure 12. Device behavior in overload condition

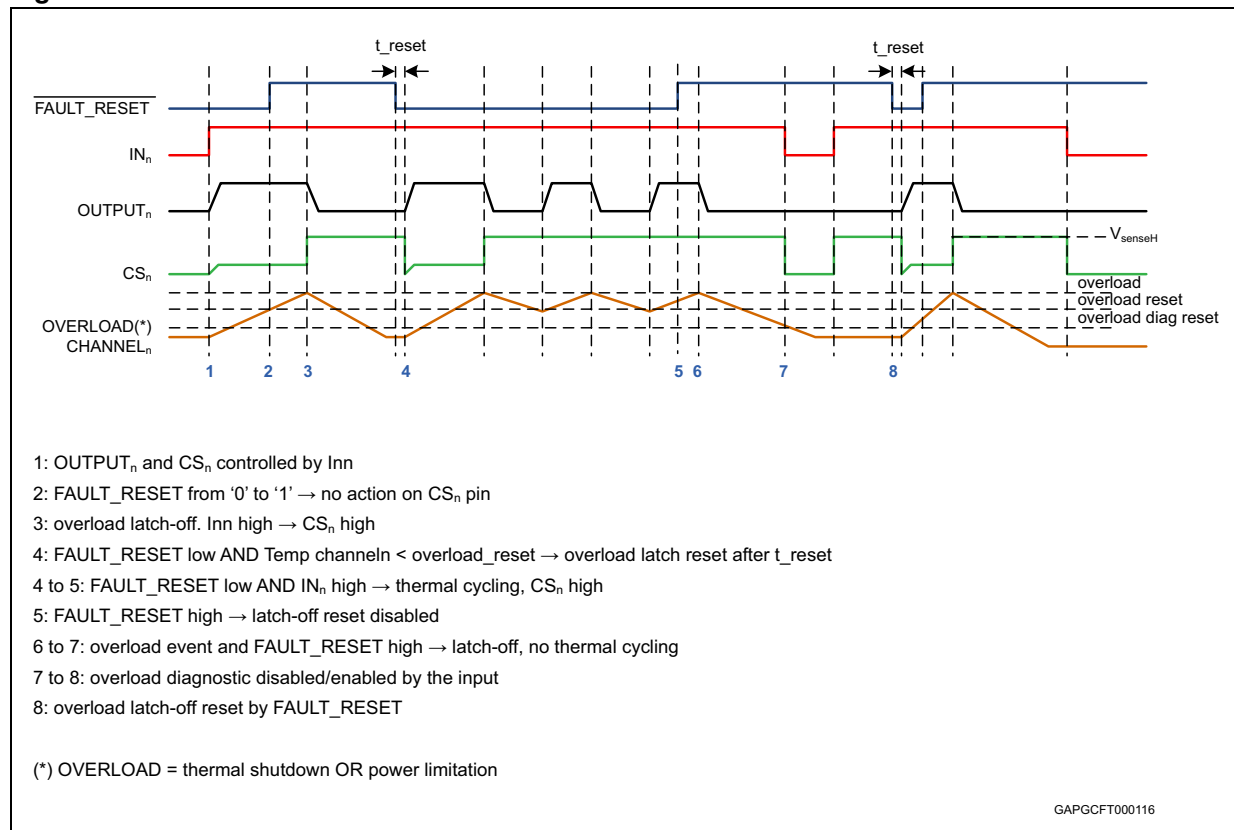




Table 11. Truth table

| Conditions                         | Fault reset standby | Input | Output   | Sense        |
|------------------------------------|---------------------|-------|----------|--------------|
| Standby                            | L                   | L     | L        | 0            |
| Normal operation                   | X                   | L     | L        | 0            |
|                                    | X                   | H     | H        | Nominal      |
| Overload                           | X                   | L     | L        | 0            |
|                                    | X                   | H     | H        | > Nominal    |
| Overtemperature / short to ground  | X                   | L     | L        | 0            |
|                                    | L                   | H     | Cycling  | $V_{SENSEH}$ |
|                                    | H                   | H     | Latched  | $V_{SENSEH}$ |
| Undervoltage                       | X                   | X     | L        | 0            |
| Short to $V_{BAT}$                 | L                   | L     | H        | 0            |
|                                    | H                   | L     | H        | $V_{SENSEH}$ |
|                                    | X                   | H     | H        | < Nominal    |
| Open-load off-state (with pull-up) | L                   | L     | H        | 0            |
|                                    | H                   | L     | H        | $V_{SENSEH}$ |
|                                    | X                   | H     | H        | 0            |
| Negative output voltage clamp      | X                   | L     | Negative | 0            |

**Table 12. Electrical transient requirements (part 1)**

| ISO 7637-2:<br>2004(E)<br>Test pulse | Test levels <sup>(1)</sup> |         | Number of<br>pulses or test<br>times | Burst cycle/pulse<br>repetition time |        | Delays and<br>impedance  |
|--------------------------------------|----------------------------|---------|--------------------------------------|--------------------------------------|--------|--------------------------|
|                                      | III                        | IV      |                                      |                                      |        |                          |
| 1                                    | - 450 V                    | - 600 V | 5000 pulses                          | 0.5 s                                | 5 s    | 1 ms, 50 $\Omega$        |
| 2a                                   | + 37 V                     | + 50 V  | 5000 pulses                          | 0.2 s                                | 5 s    | 50 $\mu$ s, 2 $\Omega$   |
| 3a                                   | - 150 V                    | - 200 V | 1h                                   | 90 ms                                | 100 ms | 0.1 $\mu$ s, 50 $\Omega$ |
| 3b                                   | + 150 V                    | + 200 V | 1h                                   | 90 ms                                | 100 ms | 0.1 $\mu$ s, 50 $\Omega$ |
| 4                                    | - 12 V                     | - 16 V  | 1 pulse                              |                                      |        | 100 ms, 0.01 $\Omega$    |
| 5b <sup>(2)</sup>                    | + 123 V                    | + 174 V | 1 pulse                              |                                      |        | 350 ms, 1 $\Omega$       |

**Table 13. Electrical transient requirements (part 2)**

| ISO 7637-2:<br>2004(E)<br>Test pulse | Test level results |    |
|--------------------------------------|--------------------|----|
|                                      | III                | IV |
| 1                                    | C                  | C  |
| 2a                                   | C                  | C  |
| 3a                                   | C                  | C  |
| 3b <sup>(1)</sup>                    | E                  | E  |
| 3b <sup>(2)</sup>                    | C                  | C  |
| 4                                    | C                  | C  |
| 5b <sup>(3)</sup>                    | C                  | C  |

1. Without capacitor between  $V_{CC}$  and GND.

2. With 10 nF between  $V_{CC}$  and GND.

3. External load dump clamp, 58 V maximum, referred to ground.

**Table 14. Electrical transient requirements (part 3)**

| Class | Contents                                                                                                                                                                 |
|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C     | All functions of the device are performed as designed after exposure to disturbance.                                                                                     |
| E     | One or more functions of the device are not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device. |

2.4 Electrical characteristics curves

Figure 13. Off-state output current

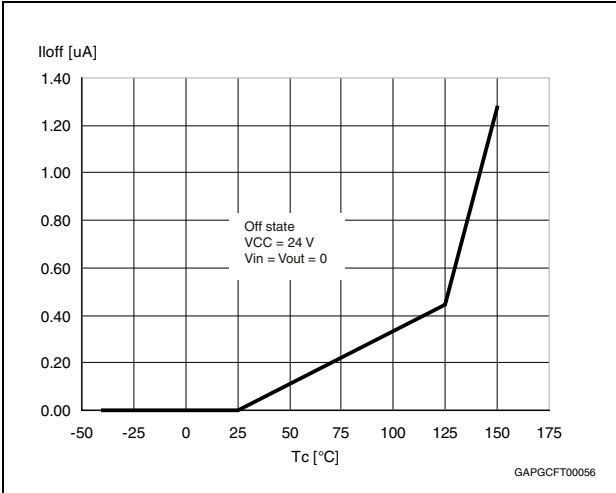


Figure 14. High level input current

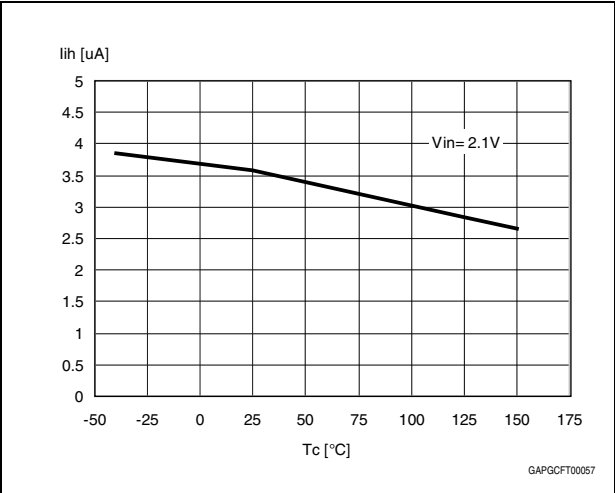


Figure 15. Input clamp voltage

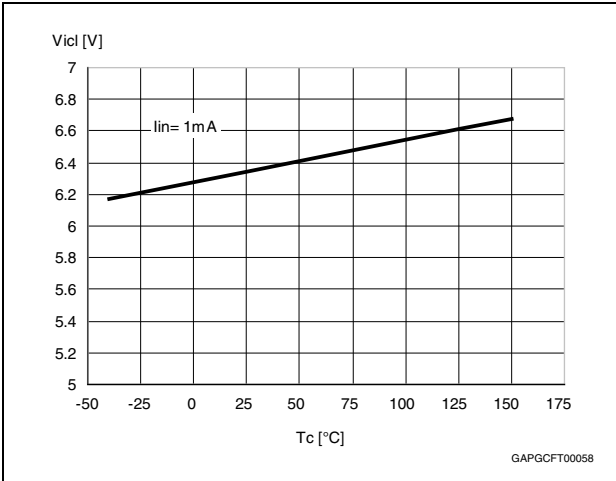


Figure 16. Input high level voltage

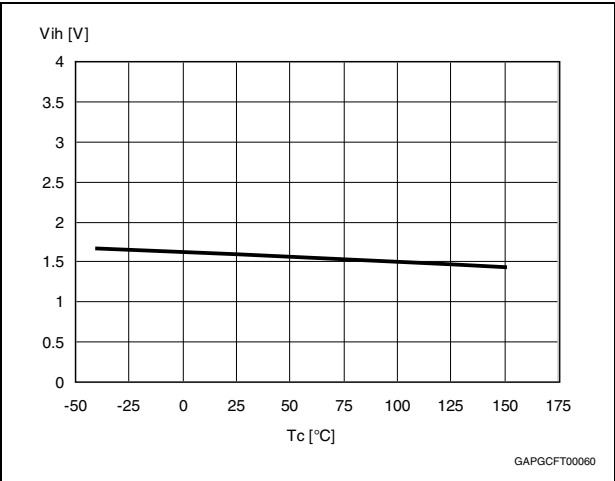


Figure 17. Input low level voltage

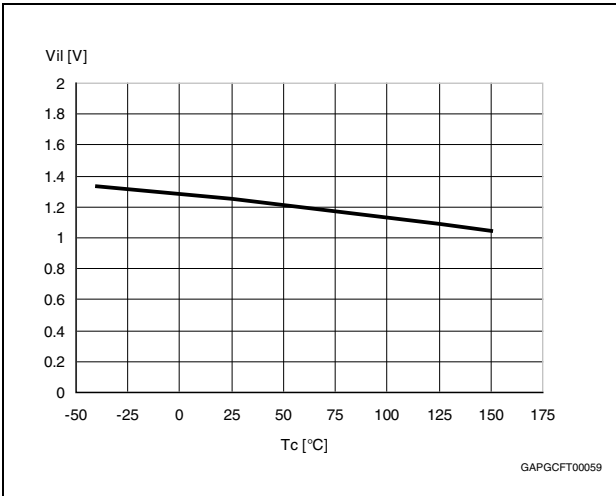


Figure 18. Input hysteresis voltage

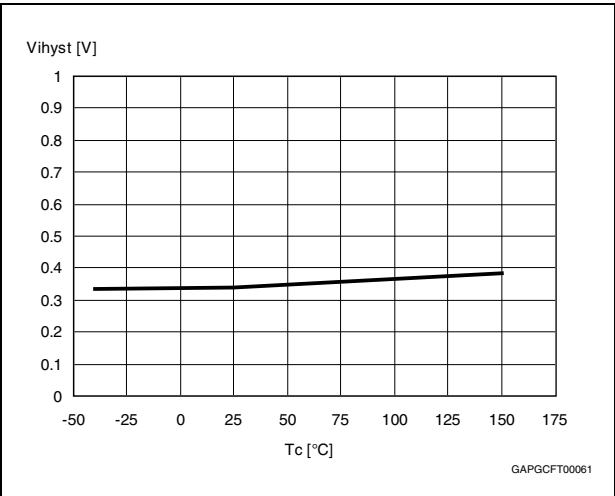


Figure 19. On-state resistance vs  $T_{case}$

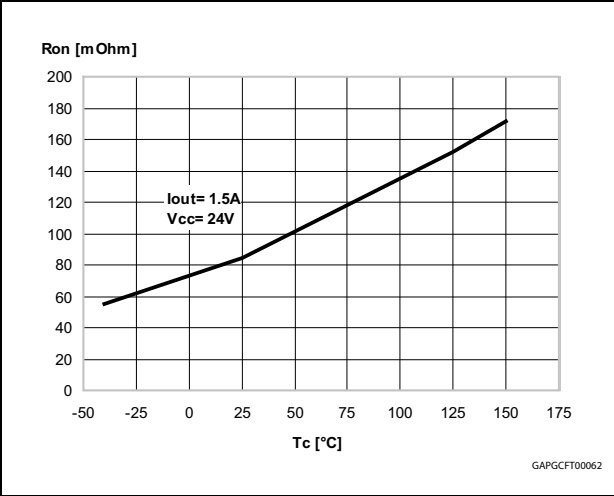


Figure 20. On-state resistance vs  $V_{CC}$

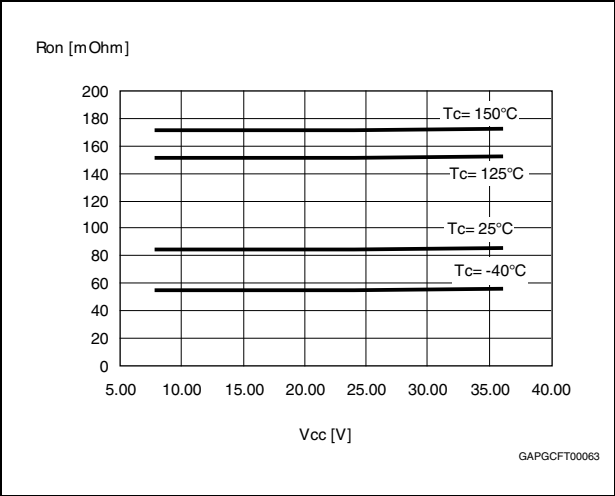


Figure 21.  $I_{LIMH}$  vs  $T_{case}$

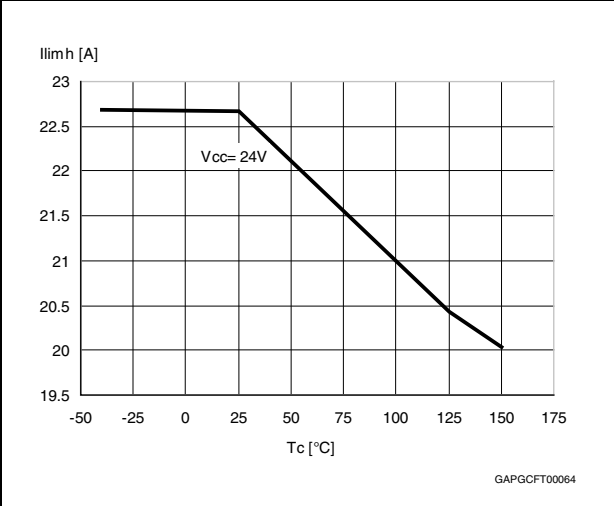


Figure 22. Turn-on voltage slope

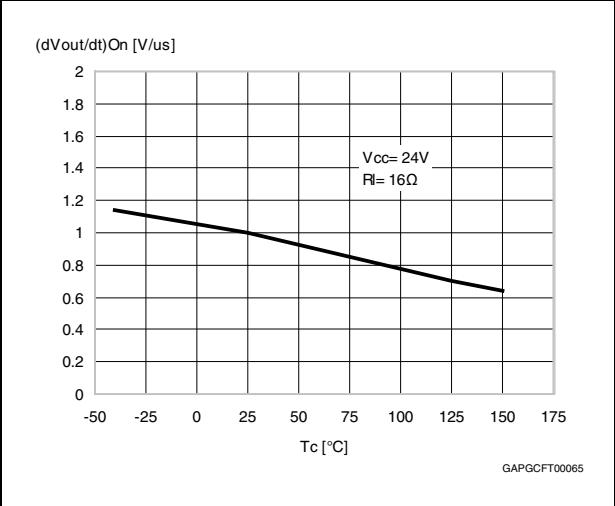
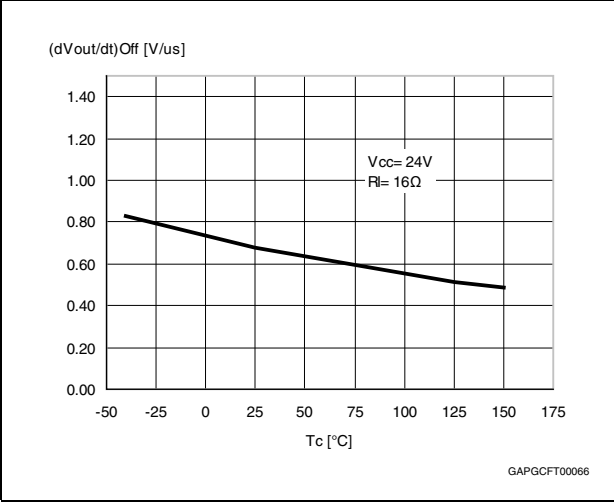
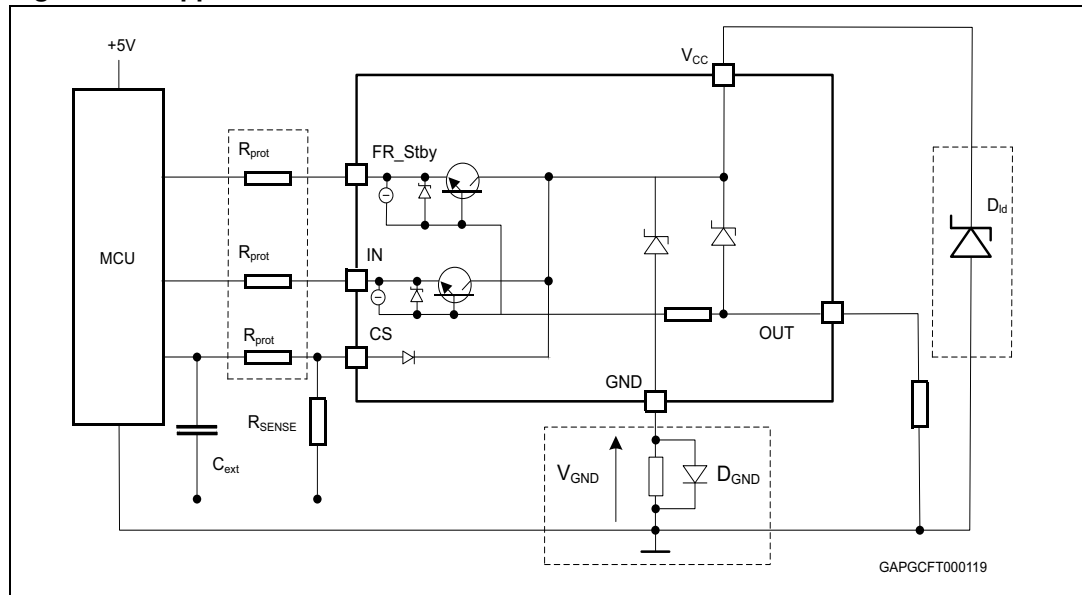


Figure 23. Turn-off voltage slope



### 3 Application information

**Figure 24. Application schematic**



### 3.1 GND protection network against reverse battery

### 3.1.1 Solution 1: resistor in the ground line ( $R_{GND}$ only)

This solution can be used with any type of load.

The following is an indication on how to dimension the  $R_{GND}$  resistor.

1.  $R_{GND} \leq 600 \text{ mV} / (I_{S(on)max})$ .
2.  $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

where  $-I_{\text{GND}}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

Power dissipation in  $R_{GND}$  (when  $V_{CC} < 0$ : during reverse battery situations) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared amongst several different HSDs. Please note that the value of this resistor should be calculated with formula (1) where  $I_{S(on)max}$  becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not shared by the device ground then the  $R_{GND}$  produces a shift ( $I_{S(on)max} * R_{GND}$ ) in the input thresholds and the status output values. This shift varies depending on how many devices are ON in the case of several high side drivers sharing the same  $R_{GND}$ .

If the calculated power dissipation leads to a large resistor or several devices have to share the same resistor then ST suggests Solution 2 is used (see below).

### 3.1.2 Solution 2: diode ( $D_{GND}$ ) in the ground line

A resistor ( $R_{GND} = 4.7 \text{ k}\Omega$ ) should be inserted in parallel to  $D_{GND}$  if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network produces a shift ( $\approx 600 \text{ mV}$ ) in the input threshold and in the status output values, if the microprocessor ground is not common to the device ground. This shift not varies if more than one HSD shares the same diode/resistor network.

## 3.2 Load dump protection

$D_{ld}$  is necessary (Voltage Transient Suppressor) if the load dump peak voltage exceeds to  $V_{CC}$  max DC rating. The same applies if the device is subject to transients on the  $V_{CC}$  line that are greater than the ones shown in the ISO T/R 7637/2 table.

## 3.3 MCU I/Os protection

If a ground protection network is used and negative transient are present on the  $V_{CC}$  line, the control pins are pulled negative. ST suggests that a resistor ( $R_{prot}$ ) be inserted in line to prevent the microcontroller I/O pins to latch-up.

The value of these resistors is a compromise between the leakage current of microcontroller and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of microcontroller I/Os.

$$-V_{CCpeak}/I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

Calculation example:

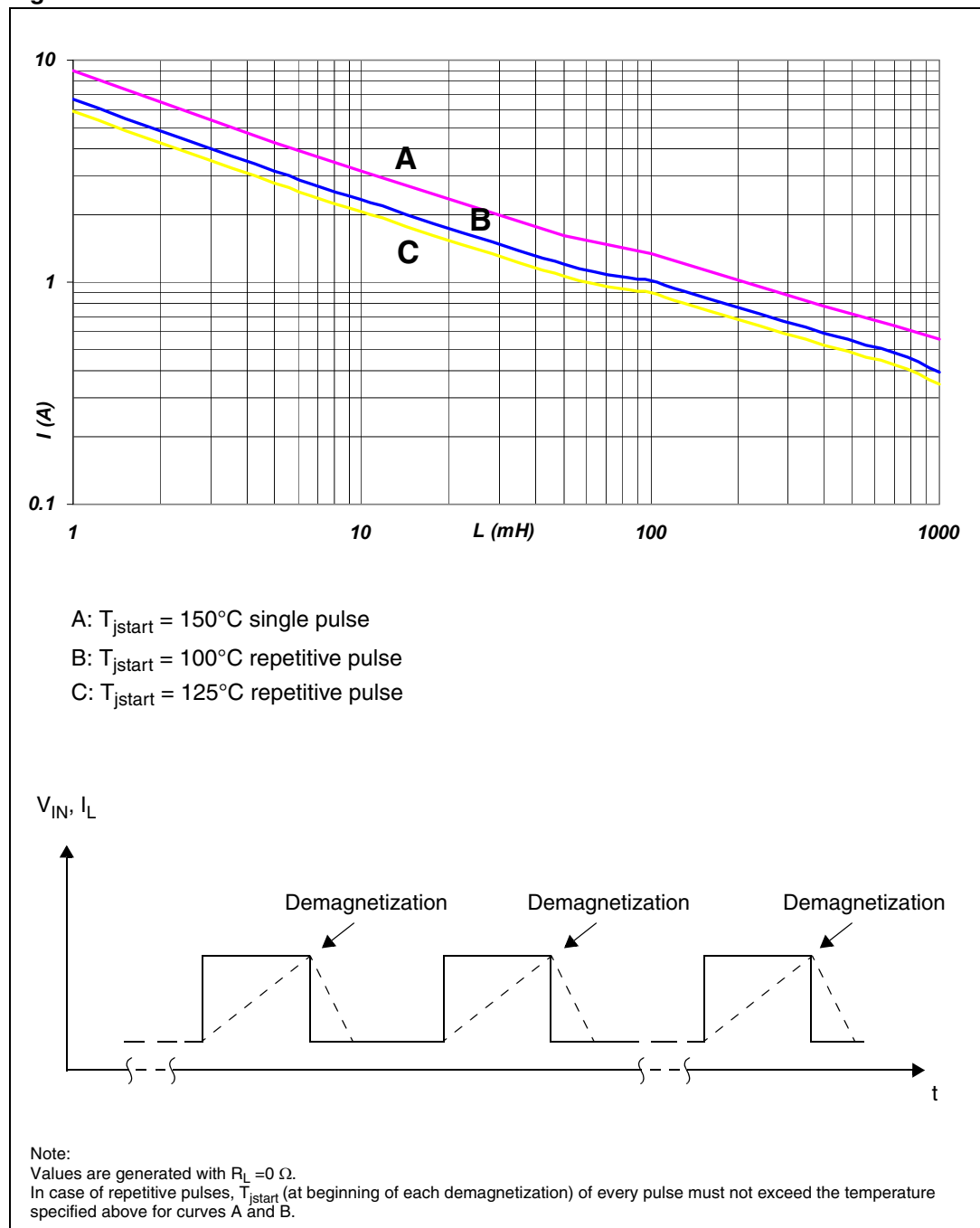
For  $V_{CCpeak} = -600 \text{ V}$  and  $I_{latchup} \geq 20 \text{ mA}$ ;  $V_{OH\mu C} \geq 4.5 \text{ V}$

$$30 \text{ k}\Omega \leq R_{prot} \leq 180 \text{ k}\Omega$$

Recommended  $R_{prot}$  value is  $60 \text{ k}\Omega$ .

### 3.4 Maximum demagnetization energy ( $V_{CC} = 24\text{ V}$ )

Figure 25. Maximum turn-off current versus inductance



# 4 Package and PCB thermal data

## 4.1 PowerSSO-12 thermal data

Figure 26. PowerSSO-12 PC board

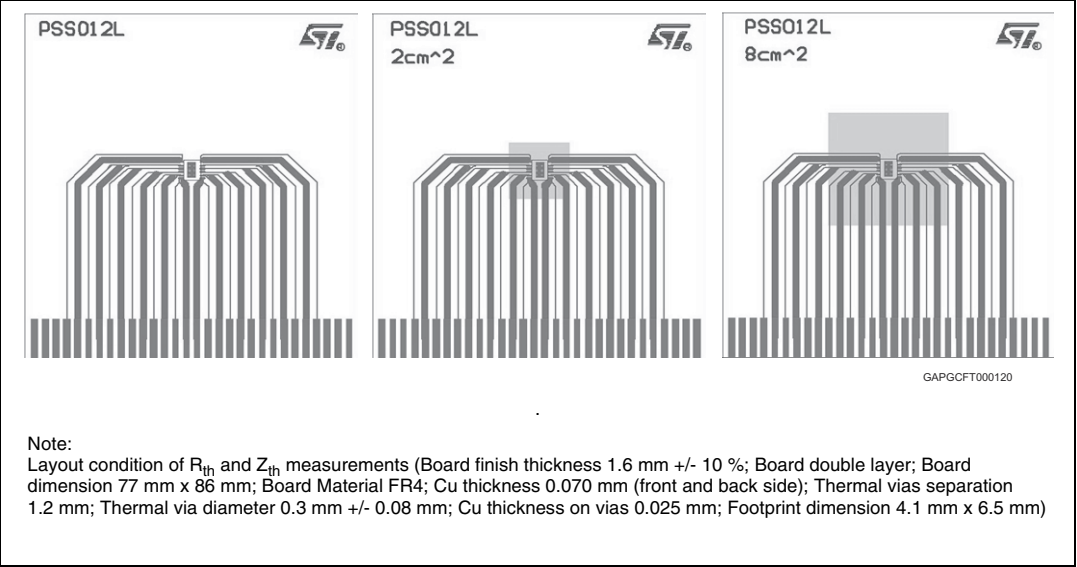
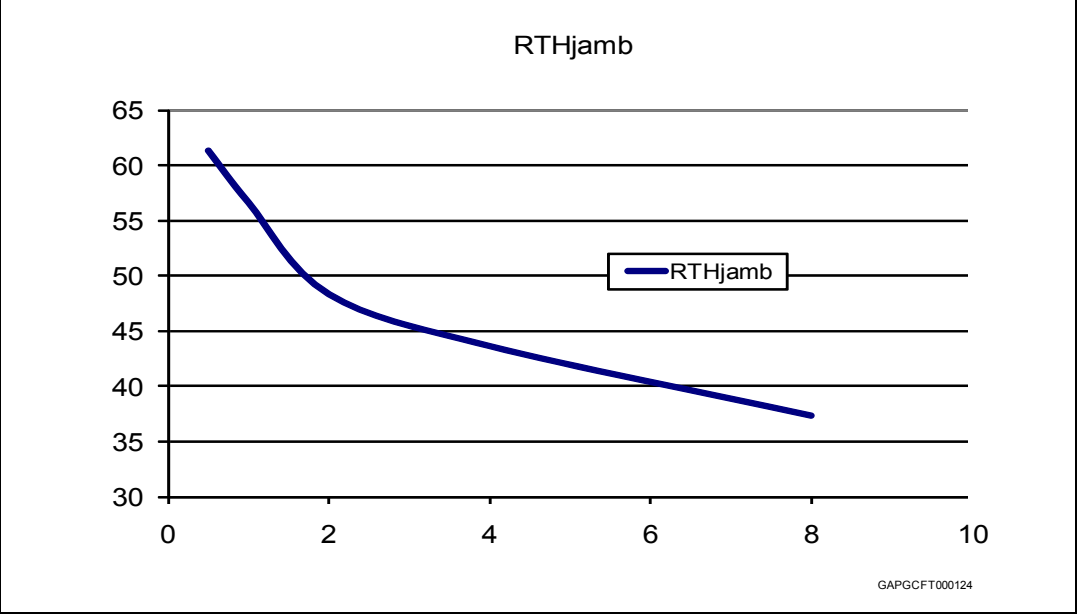
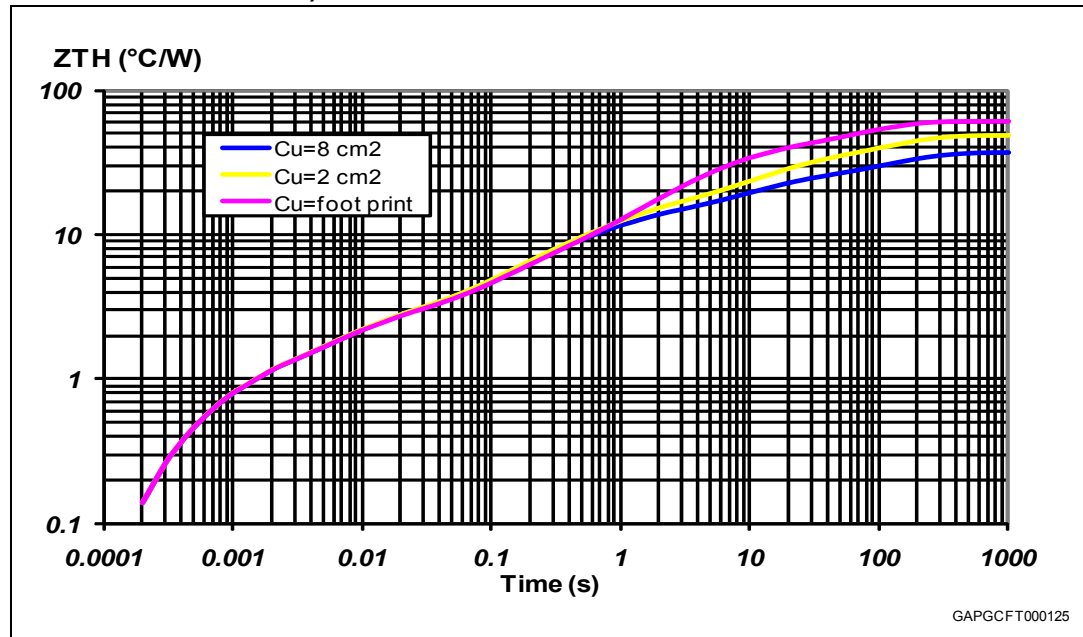


Figure 27.  $R_{thj-amb}$  vs PCB copper area in open box free air condition (one channel ON)

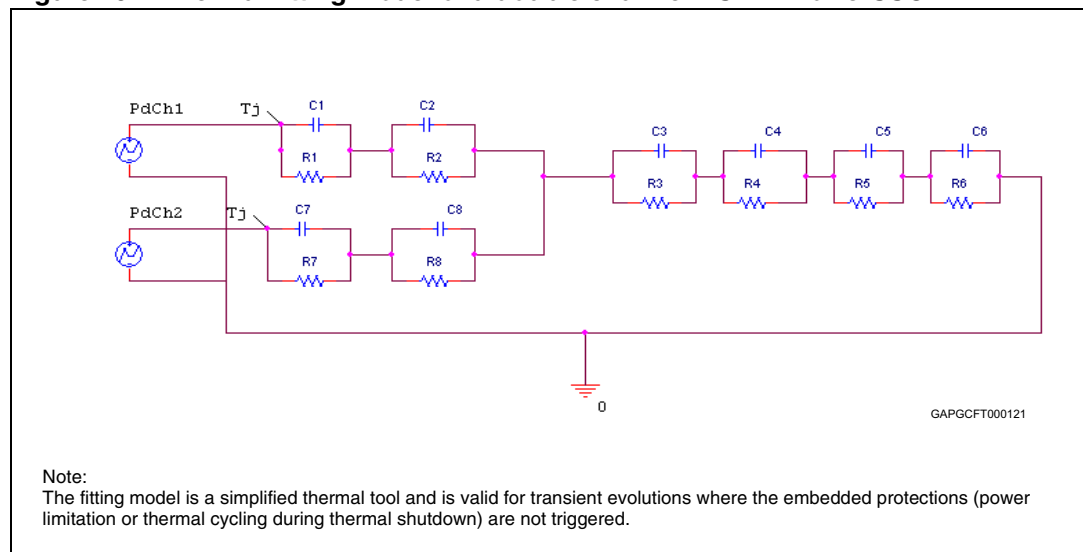




**Figure 28. PowerSSO-12 thermal impedance junction ambient single pulse (one channel ON)**



**Figure 29. Thermal fitting model of a double channel HSD in PowerSSO-12**



#### Equation 1: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

$$\text{where } \delta = t_p / T$$

**Table 15. Thermal parameters**

| Area/island (cm <sup>2</sup> ) | Footprint | 2   | 8   |
|--------------------------------|-----------|-----|-----|
| R1 = R7 (°C/W)                 | 0.8       |     |     |
| R2 = R8 (°C/W)                 | 1.5       |     |     |
| R3 (°C/W)                      | 3         |     |     |
| R4 (°C/W)                      | 8         | 8   | 7   |
| R5 (°C/W)                      | 22        | 15  | 10  |
| R6 (°C/W)                      | 26        | 20  | 15  |
| C1 = C7 (W.s/°C)               | 0.0008    |     |     |
| C2 = C8 (W.s/°C)               | 0.005     |     |     |
| C3 (W.s/°C)                    | 0.05      |     |     |
| C4 (W.s/°C)                    | 0.2       | 0.1 | 0.1 |
| C5 (W.s/°C)                    | 0.27      | 0.8 | 1   |
| C6 (W.s/°C)                    | 3         | 6   | 9   |

## 5 Package and packing information

### 5.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).

ECOPACK® is an ST trademark.

### 5.2 PowerSSO-12 mechanical data

Figure 30. PowerSSO-12 package dimensions

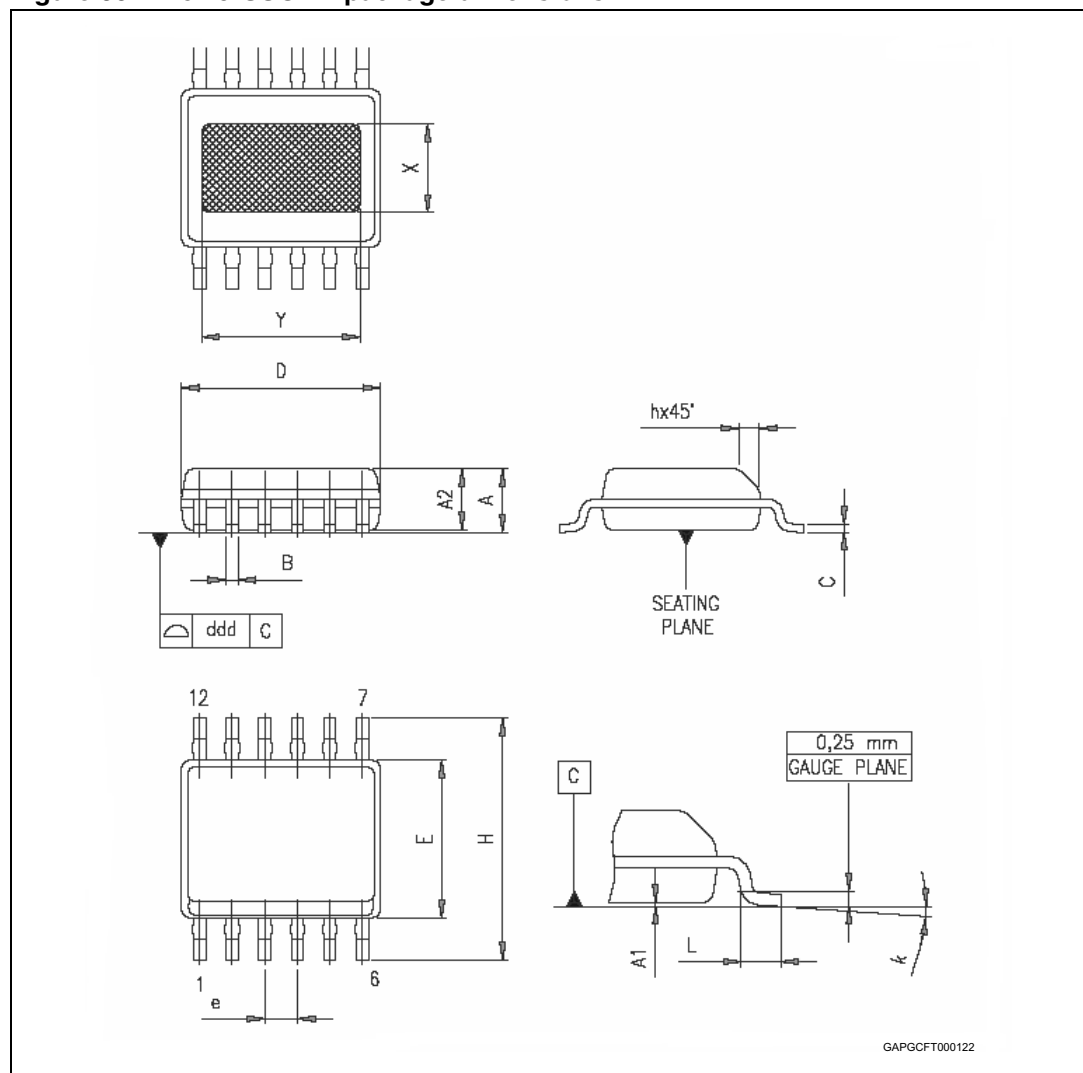
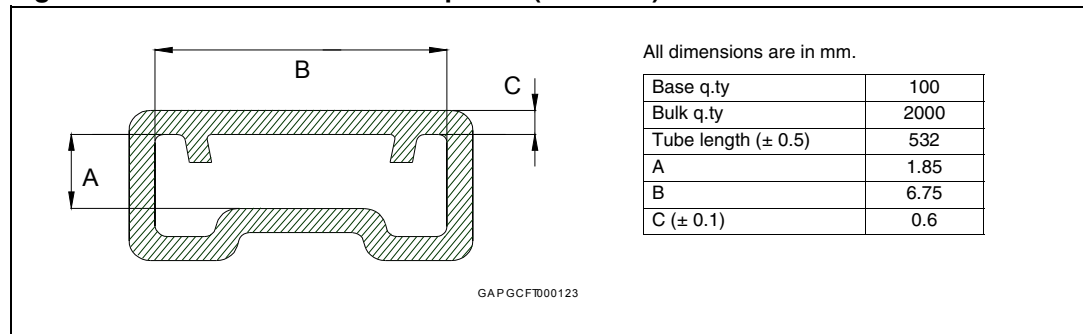


Table 16. PowerSSO-12 mechanical data

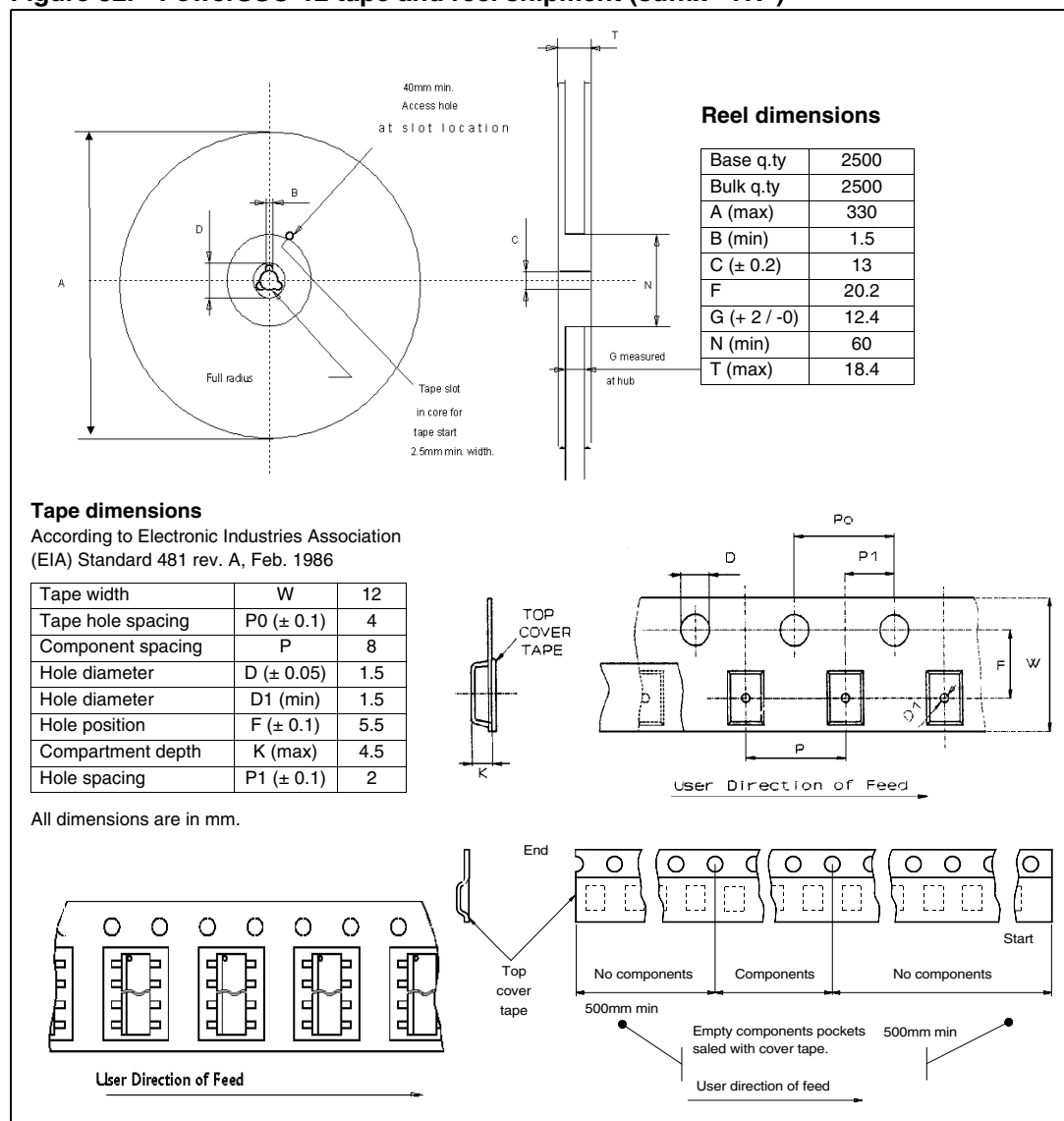
| Symbol | Millimeters |       |       |
|--------|-------------|-------|-------|
|        | Min.        | Typ.  | Max.  |
| A      | 1.250       | -     | 1.620 |
| A1     | 0.000       | -     | 0.100 |
| A2     | 1.100       | -     | 1.650 |
| B      | 0.230       | -     | 0.410 |
| C      | 0.190       | -     | 0.250 |
| D      | 4.800       | -     | 5.000 |
| E      | 3.800       | -     | 4.000 |
| e      | -           | 0.800 | -     |
| H      | 5.800       | -     | 6.200 |
| h      | 0.250       | -     | 0.500 |
| L      | 0.400       | -     | 1.270 |
| k      | 0°          | -     | 8°    |
| X      | 2.200       | -     | 2.800 |
| Y      | 2.900       | -     | 3.500 |
| ddd    | -           | -     | 0.100 |

### 5.3 Packing information

**Figure 31. PowerSSO-12 tube shipment (no suffix)**



**Figure 32. PowerSSO-12 tape and reel shipment (suffix “TR”)**



## 6 Order code

**Table 17. Device summary**

| Package     | Order codes  |                |
|-------------|--------------|----------------|
|             | Tube         | Tape and reel  |
| PowerSSO-12 | VND5T100AJ-E | VND5T100AJTR-E |

## 7 Revision history

**Table 18. Document revision history**

| Date        | Revision | Changes             |
|-------------|----------|---------------------|
| 08-Mar-2011 | 1        | Initial release.    |
| 25-Sep-2013 | 2        | Disclaimer updated. |

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